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CONFIRMATION NO. 8582

<b>SERIAL NUMBER</b> 10/686,893	<b>FILING OR 371(c) DATE</b> 10/16/2003 <b>RULE</b>	<b>CLASS</b> 438	<b>GROUP ART UNIT</b> 2823	<b>ATTORNEY DOCKET NO.</b> YAO-3990US3
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**APPLICANTS**

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**\*\* CONTINUING DATA \*\*\*\*\***

This application is a CON of 10/293,154 11/13/2002 ABN which is a CON of 09/484,473 01/18/2000 PAT 6,620,738  
 which is a DIV of 09/116,725 07/16/1998 ABN ✓ QVJ

**\*\* FOREIGN APPLICATIONS \*\*\*\*\***

JAPAN 9-191179 07/16/1997 ✓ QVJ

**IF REQUIRED, FOREIGN FILING LICENSE**

**GRANTED \*\* 01/14/2004**

Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no	<b>STATE OR COUNTRY</b> JAPAN	<b>SHEETS DRAWING</b> 5	<b>TOTAL CLAIMS</b> 12	<b>INDEPENDENT CLAIMS</b> 1
35 USC 119 (a-d) conditions met <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance				
Verified and Acknowledged	Examiner's Signature <i>[Signature]</i>	Initials <i>QVJ</i>		

**ADDRESS**

23122

**TITLE**

Etchant and method for fabricating a semiconductor device using the same

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